

Lift of degeneracy of Landau levels of 2D electron gas by point-like impurities

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We study the density of states of two-dimensional electron gas in magnetic field with scattering on point-like impurities that are uniformly distributed along the sample. We show that the electron-impurity interaction completely lifts the degeneracy of the Landau levels even at low impurity concentration. This statement is in contradiction with the previous results obtained in the unphysical approximation of two-dimensional impurities. There is a large region of the electron energy ω , counted from the Landau level, where the density of states $\rho(\omega)$ is inversely proportional to $|\omega|$ and proportional to the impurity concentration. Our results are applicable to different 2D electron systems as heterostructures, inversion layers and interfaces of condensed media.

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1. Two-dimensional (2D) electron systems are realized on interfaces of two condensed media. The typical examples of such systems are heterostructures [2], electrons on the helium surface [1] and in inversion layers. In magnetic field the spectrum of the 2D electrons is discrete and infinitely degenerate. We consider the question of removal of this degeneracy due to interaction of electrons with point-like impurities. There is an opinion that at low surface concentration n_s of these impurities the infinite degeneracy the Landau levels is lifted only partially [3]. More precisely if $n_s < \frac{1}{2\pi l_H^2}$ the degeneracy of the Landau levels is $\frac{S}{2\pi l_H^2} - N$. Here $N = n_s S$ is the total number of impurities, S is the surface accessible for electrons, $l_H = \hbar c/eH$ is the magnetic length. In this case N electrons separate from each Landau level and form the impurity band. The proof of this statement [3] is based on the possibility to determine the wave function of electrons on the

Landau level in such a way that it is zero at the points where the impurities are situated. If the impurities are point-like they do not influence the spectrum of $\frac{S}{2\pi l_H^2} - N$ electron states. However, such a conclusion need the surface impurity density n_S to be determined. The problem is that the 2D electron systems are usually open. The electron motion along the z axis which is perpendicular to the conducting planes is characterized by the wave function $\varphi(z)$ which is confined on the macroscopic scale z_∞ that depends on the geometry of sample. The typical wave function $\varphi(z)$ has the form [1, 2]

$$\varphi^2(z) = \frac{1}{2z_0} z_*^2 e^{-z_*} \quad \text{at } 0 < z < z_\infty \quad (1)$$

$$\varphi(z) = 0 \quad \text{at } z < 0, \quad z_* \equiv z/z_0$$

Electrons can move in the region $0 < z < z_\infty$ (not only in $z \leq z_0$). Hence, even at low bulk concentration n_{imp} of impurities their surface density $n_S = n_{imp} z_\infty$ is very large (the effective interaction of electrons with an impurity now depends on the distance of this impurity from the conducting plane). Usually one can put $n_S = \infty$. Hence, the infinite degeneracy of the Landau levels is lifted completely by the point-like impurities. In other words the number of impurities is small in the region $z \leq z_0$, but large in the region $z < z_\infty$: $C_\infty = C_0 \frac{z_\infty}{z_0} \gg 1$. This situation usually takes place on experiment [1], [2]. For electrons on the liquid helium surface the heavy atoms of helium vapor play the role of impurities. Below we calculate the electron density ρ at low impurity concentration $C_0 \equiv n_{imp} 2\pi l_H^2 z_0 \ll 1$.

2. The density of states $\rho(E)$ is related to the imaginary part of the electron Green's function $G(r, r', E)$ by the relation $\rho(E) = \frac{-1}{\pi} \text{Im} G(E)$, where $G(E) = \int d^3r G(r, r, E)$ [4]. Since the electron system is uniform along the conducting (x, y) plane, the Green's function does not depend on (x, y) : $G(r, r, E) = G(z, E) = G(E)\varphi^2(z)$. The last equality is because all electrons are on the lowest dimensional energy in z -direction level and have the same wave function $\varphi^2(z)$. The magnetic field H is assumed to be strong so that the electron interaction with impurities $V(\mathbf{r})$ does not mix the wave functions of electrons on different Landau levels. Hence, the density of states $\rho(E)$ depends only on the quantity $\omega \equiv E - \varepsilon_0 - (n + 1/2)\omega_c$, where ε_0 is the energy of the dimensional quantization along the z -axis and ω_c is the cyclotron energy. The interaction potential of electrons with point-like impurities is

$$V(\mathbf{r}) = u_0 \sum_i \delta(x - x_i) \delta(y - y_i) \delta(z - z_i) \quad (2)$$

Here x, y, z, x_i, y_i, z_i are the electron and impurity coordinates. The scattering

length

$$a = -\frac{m}{2\pi\hbar^2}u_0. \quad (3)$$

The Green's function $G(\omega)$ is related to the unperturbed Green's function $G_0(\omega)$ of clean electron system by the well-known formula [4]

$$G(\omega) = \frac{1}{G_0^{-1}(\omega) - \Sigma(\omega)}, \quad G_0(\omega) = \frac{1}{\omega}. \quad (4)$$

The function $\Sigma(\omega)$ (4) is [5, 4, 6].

$$\Sigma(\omega) = u_0 n_{imp} \int_0^{z_\infty} \frac{\varphi_0^2(z) dz}{1 - \frac{u_0}{2\pi l_H^2} \varphi_0^2(z) G(\omega)} \quad (5)$$

This expression corresponds to the summation of all diagrams without intersection of impurity lines [6] and subsequent averaging over the impurity positions. The formulas (4,5) are valid only for point-like impurities (2). It is convenient to determine the reduced wave function φ_* of perpendicular-to-layers electron motion:

$$\varphi_0^2(z) = \frac{1}{z_0} \varphi_*^2(z_*), \quad z_* \equiv \frac{z}{z_0}, \quad \int \varphi_*^2(z_*) dz_* = 1, \quad (6)$$

where z_0 – is the characteristic scale of the function $\varphi_0(z)$. From (3), (5), (6) we get

$$\Sigma(\omega) = -G^{-1}(\omega) C_0 J(\omega); \quad J(\omega) \equiv \int_0^{z_\infty/z_0} \frac{\varphi_*^2(z_*) dz_*}{\varphi_*^2(z_*) - \frac{1}{\omega_0 G(\omega)}} \quad (7)$$

where $C_0 \equiv 2\pi l_H^2 z_0 n_{imp}$; $\omega_0 \equiv -\frac{a}{z_0} \omega_c$.

3. At the beginning we consider the first order in the impurity concentration. Thus we replace the exact Green's function in formulas (5), (7) by the unperturbed Green's function $G_0 = 1/\omega$. This approximation means the summation of all diagrams corresponding to the scattering on one impurity. From (4), (7) one sees, that the Green's function G formally has a pole at $\omega = 0$:

$$G = \frac{1}{\omega[1 + C_0 J(\omega)]}. \quad (8)$$

However, as follows from (7), at $\omega \rightarrow 0$ the integral over z_* diverges, that leads to the small value of the residue at this pole:

$$\frac{1}{\pi} \text{Im}G(\omega) = \delta(\omega) \frac{1}{1 + C_\infty}; \quad C_\infty = C_0 \frac{z_\infty}{z_0} \quad (9)$$

For $z_\infty = \infty$ the residue is zero and the infinite degeneracy of the Landau levels is lifted completely even in the first order in the impurity concentration. The density of states $\rho(\omega)$ is determined by the function $J(\omega)$ (7)

$$\rho(\omega) = \frac{-C_0 \text{Im} J(\omega)}{\pi \omega [(1 + C_0 \text{Re} J(\omega))^2 + C_0^2 \text{Im}^2 J(\omega)]} \quad (10)$$

First, we consider the model case when the reduced wave function φ_* has the form

$$\begin{aligned} \varphi_*^2(z_*) &= e^{-z_*} & z_* > 0 \\ \varphi_*^2(z_*) &= 0 & z_* < 0. \end{aligned} \quad (11)$$

This wave function corresponds to the boundary condition at $z = 0$ for narrow and deep potential well. The function $J(\omega)$ (7) becomes

$$J(\omega) = \ln \frac{\omega - \omega_0}{\omega}. \quad (12)$$

Assuming that there is only one type of repulsive impurities, from (10), (12) we obtain

$$\rho(\omega) = \frac{C_0}{\omega \left[\left(1 + C_0 \ln \frac{\omega_0 - \omega}{\omega} \right)^2 + C_0^2 \pi^2 \right]}. \quad (13)$$

The density of states $\rho(\omega)$ is determined by the cut (not a pole) of the Green's function $G(\omega)$. Using the definition of ω_0 (7), we get the criterion when the electron-impurity interaction $V(\mathbf{r})$ (3) is weak: $a \ll z_0$. Hence, if the scattering length of electron on impurity is less than the characteristic scale of the quantization along z -axis, the one Landau level approximation can be used, and the density of states from different Landau levels does not intersect. From (13) it follows that in the wide region of ω the density of states is inversely proportional to ω :

$$\rho(\omega) = \frac{C_0}{\omega}, \quad C_0 \ln \frac{\omega_0}{\omega} \ll 1 \quad (14)$$

Up to the terms $\sim C_0^2$ the integral

$$\int_0^{\omega_0} \rho(\omega) d\omega \cong \int_0^{\omega_0} \frac{C_0 d\omega}{\omega [1 + C_0 \ln \frac{\omega_0 - \omega}{\omega}]^2} \cong 1. \quad (15)$$

Hence, after switching on the electron-impurity interaction the total number of electron states does not change, while the δ -shape pike of the unperturbed density

of states is absent. This means that at any small value of ω there is an impurity with coordinate $z_i = z_0 \ln \frac{\omega_0}{\omega} \gg z_0$, that lift the Landau level degeneracy. These statements do not depend on the exact shape of the wave function $\varphi(z)$. For more physical $\varphi(z)$ (1) the density of states $\rho(\omega)$ is given by the formula similar to (13) at $\omega \ll \omega_0$ up to the terms of the order $\ln \ln \frac{\omega_0}{\omega}$. The dependence $\varphi(z) \sim e^{-z/z_0}$ at $z \gg z_0$ is important here. Moreover, there is always a wide region ω , where $\rho(\omega)$ is inversely proportional to ω . For example, for the wave function of harmonic oscillator $\varphi_*(z_*) \sim e^{-z_*^2}$ from (10) and (7) at $\omega \ll \omega_0$ we get:

$$\rho(\omega) = \frac{C_0}{2\omega(\ln \frac{\omega_0}{\omega})^{1/2}[1 + C_0(\ln \frac{\omega_0}{\omega})^{1/2}]^2}. \quad (16)$$

In the case of strong electric field that clamps the electrons to the interface of two media: $\varphi_*^2(z_*) \sim e^{-z_*^{3/2}}$ and from (10) at $\omega \ll \omega_0$ we have

$$\rho(\omega) = \frac{2C_0}{3\omega(\ln \frac{\omega_0}{\omega})^{1/3}[1 + C_0(\ln \frac{\omega_0}{\omega})^{2/3}]^2}. \quad (17)$$

So, for the open electron systems the electron-impurity interaction lifts completely the degeneracy of the Landau levels. The density of states $\rho(\omega)$ in the first order in the impurity concentration is given by Eq. (13)-(17). The generalization to the case of several types of impurities is trivial. For example, the analogue of (14) is

$$\begin{aligned} \rho(\omega) &= \frac{C_-}{\omega} & \omega > 0 \\ \rho(\omega) &= \frac{C_+}{|\omega|} & \omega < 0 \end{aligned} \quad (18)$$

where C_- and C_+ are the total concentration of repulsive and attractive impurities.

4. The formulas $\rho(\omega)$ (13)-(17) are valid at

$$\omega_0 e^{-1/C_0} \ll \omega, \quad \omega_0 - \omega \gg e^{-1/C_0}. \quad (19)$$

Beyond this region the terms of the next orders in C_0 are important, since they are multiplied by the large logarithm $\ln[(\omega_0 - \omega)/\omega]$. To study the Green's function in a wider region over ω let us consider the self-consistent approximation, given by formulas (4), (5), (7). After substitution of (11) to (7) and (4) we get an equation for G :

$$G = \frac{1}{\omega} [1 - C_0 \ln(1 - \omega_0 G)]. \quad (20)$$

At $\omega \ll \omega_0$, $\omega_0 G \gg 1$ the equation (20) can be simplified:

$$G = \frac{-C_0}{\omega} [\ln(-\omega_0 G) - 1/C_0] = \frac{-C_0}{\omega} \ln \left(-\frac{e\omega_N G}{C_0} \right), \quad (21)$$

where we have introduced the new scale of energy $\omega_N \equiv \omega_0 \exp(-1/C_0)C_0/e$. It is convenient to define the new function $y \equiv -\omega G/C_0$. The equation (21) takes the form:

$$y = \ln(y \omega_N/\omega) + 1, \quad (22)$$

From this equation it follows that y depends only on one variable: $y = y(\omega/\omega_N)$. Let us separate the real and imaginary parts of this function: $y = A + iB$. From (22) we get the system of two equations on real functions A and B , that can be simplified to:

$$\begin{aligned} A &= B/\tan B \\ e^{B/\tan B} \frac{\sin B}{B} &= \frac{\omega_N e}{\omega} \end{aligned} \quad (23)$$

The last equation determines the density of states $\rho(\omega) = C_0 B/\pi\omega$. We need the solution $B(\omega/\omega_N) \geq 0$. The function $B(\omega/\omega_N)$ monotonically increase from zero at $\omega = \omega_N$ to $B = \pi$ at $\omega/\omega_N \rightarrow \infty$. Near $\omega = \omega_N$ the function $B \approx \sqrt{2(\omega - \omega_N)/(\omega_N)}$. At $\omega_N \ll \omega \ll \omega_0$ up to double logarithmic terms in ω/ω_N the function $B = \pi[1 - 1/\ln(\omega/\omega_N)]$. So, at $\omega \ll \omega_0$ the density of states is given by the universal function of ω/ω_N . At $C_0 \ll 1$ the asymptotics of this function are:

$$\begin{aligned} \omega\rho(\omega)/C_0 &= \sqrt{2(\omega - \omega_N)/(\omega_N)}/\pi, \quad at\omega - \omega_N \ll \omega_N; \\ \omega\rho(\omega)/C_0 &= 1 - 1/\ln(\omega/\omega_N), \quad at\omega \gg \omega_N. \end{aligned} \quad (24)$$

Let us consider the region $|\omega - \omega_0| \ll \omega_0$, where in first order on C_0 we had singularity of $ImG_0(\omega)$. The solution $G(\omega)$ of self-consistent equation (4),(5) does not have this singularity and monotonically falls to zero at $\omega = \omega_x = \omega_0(1 + x_0)$, where x_0 is the solution of algebraic equation $x_0 = C_0[\ln(1/C_0) + 1 + \ln(1 + x_0)]$. At $C_0 \ll 1$ we have

$$x_0 \approx C_0[\ln(1/C_0) + 1 + C_0 \ln(1/C_0)].$$

In the vicinity of $\omega = \omega_x$ $B(\omega) \approx \sqrt{2(\omega_x - \omega)[1/(\omega_0 C_0) - 1/\omega_x]}$. On Fig. 1 we plot the reduced density of states $(\omega/C_0)\rho(\omega/\omega_0) = B/\pi$ for three different values of impurity concentration. One sees that at $\omega \ll \omega_0$ all three plots, while being shifted with ω_N , have universal shape. The obtained solution give the right behavior of the density of states $\rho(\omega)$ until it goes to zero, i.e. in the region $\omega_N < \omega < \omega_x$.

Beyond this interval there are "tails" of the density of states, that are presumably exponentially small and can be found only after taking into account the diagrams with intersection of the impurity lines.

In conclusion we remark that the proposed model disagrees with the existing conception. Some exact results of the theory of electron-impurity interaction in 2D electron systems are obtained in [8, 9, 10]. However, in these works the two-dimensional point-like impurities were considered, and the interaction potential $V(r)$ (2) had the form

$$V(r) = u_0 \delta(x - x_i) \delta(y - y_i). \quad (25)$$

Since the z -coordinate does not enter here, this potential corresponds to the δ -shaped thread, but not to a point-like impurity. Our consideration takes three-dimensional point-like impurities. If one does not integrate over z -coordinate with the impurity distribution function and the wave function of electrons, one comes to the unphysical limit of δ -shaped threads.

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Figure caption: The reduced density of states $\omega\rho(\omega)/C_0$ in logarithmic scale for three different values of the impurity concentration: $C_0 = 0.2$ (solid line), $C_0 = 0.1$ (dot line) and $C_0 = 0.05$ (dash lie). For each curve the value ω_N is marked. Near $\omega = \omega_N$ the reduced density of states is an universal function of ω/ω_N .

